## NSN 5961-00-088-2783

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-088-2783 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, collector-to-base, emitter open and 50.0 collector to emitter voltage/static/base open and 75.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 5.00 amperes source cutoff current and 5.00 amperes source cutoff current **Transfer Ratio:** 40.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 pin and 1 case **Specification Data:** 80131-release2903 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**